

Schottky Diode

$$V_{RRM} = 150\text{ V}$$

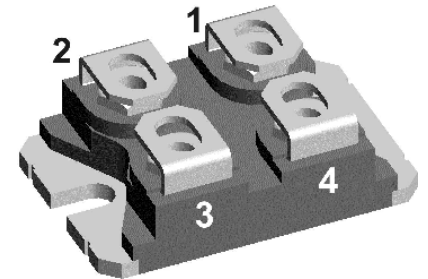
$$I_{FAV} = 2 \times 100\text{ A}$$

$$V_F = 0.77\text{ V}$$

High Performance Schottky Diode
 Low Loss and Soft Recovery
 Parallel legs

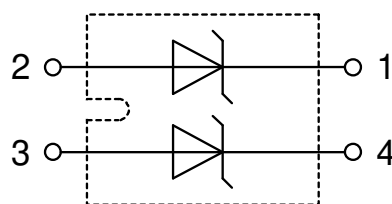
Part number

DSS2x101-015A



Backside: isolated

 E72873



Features / Advantages:

- Very low V_f
- Extremely low switching losses
- Low I_{rm} values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

Package: SOT-227B (minibloc)

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0
- Base plate: Copper internally DCB isolated
- Advanced power cycling

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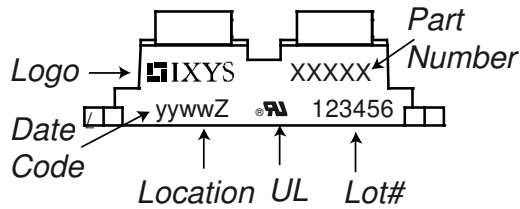


| Schottky | | | | Ratings | | | |
|------------|--|--|------------------------------|-----------------------------|------|------|------|
| Symbol | Definition | Conditions | | min. | typ. | max. | Unit |
| V_{RSM} | max. non-repetitive reverse blocking voltage | | | | | 150 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | | | | | 150 | V |
| I_R | reverse current, drain current | $V_R = 150\text{ V}$ | $T_{VJ} = 25^\circ\text{C}$ | | | 4 | mA |
| | | $V_R = 150\text{ V}$ | $T_{VJ} = 125^\circ\text{C}$ | | | 10 | mA |
| V_F | forward voltage drop | $I_F = 100\text{ A}$ | $T_{VJ} = 25^\circ\text{C}$ | | | 0.91 | V |
| | | | | | | 1.09 | V |
| | | $I_F = 200\text{ A}$ | $T_{VJ} = 125^\circ\text{C}$ | | | 0.77 | V |
| | | | | | | 0.99 | V |
| I_{FAV} | average forward current | $T_C = 110^\circ\text{C}$ rectangular | $T_{VJ} = 150^\circ\text{C}$ | d = 0.5 | | 100 | A |
| | | | | | | | |
| V_{FO} | threshold voltage | for power loss calculation only | | | | 0.53 | V |
| r_F | slope resistance | | | | | 2.1 | mΩ |
| R_{thJC} | thermal resistance junction to case | | | | | 0.4 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | | 0.1 | | K/W |
| P_{tot} | total power dissipation | | | $T_C = 25^\circ\text{C}$ | | 310 | W |
| I_{FSM} | max. forward surge current | t = 10 ms; (50 Hz), sine; $V_R = 0\text{ V}$ | | $T_{VJ} = 45^\circ\text{C}$ | | 1.40 | kA |
| C_J | junction capacitance | $V_R = 24\text{ V}$ f = 1 MHz | | $T_{VJ} = 25^\circ\text{C}$ | | 962 | pF |



| Package SOT-227B (minibloc) | | | | Ratings | | | |
|-----------------------------|--|----------------------|-------------------------------------|---------|------|------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| I_{RMS} | RMS current | per terminal | | | 150 | A | |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C | |
| T_{op} | operation temperature | | -40 | | 125 | °C | |
| T_{stg} | storage temperature | | -40 | | 150 | °C | |
| Weight | | | | | 30 | g | |
| M_D | mounting torque | | 1.1 | | 1.5 | Nm | |
| M_T | terminal torque | | 1.1 | | 1.5 | Nm | |
| $d_{Spp/APP}$ | creepage distance on surface striking distance through air | terminal to terminal | 10.5 | 3.2 | | mm | |
| $d_{Spb/APb}$ | | terminal to backside | 8.6 | 6.8 | | mm | |
| V_{ISOL} | isolation voltage | t = 1 second | | 3000 | | V | |
| | | t = 1 minute | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 2500 | | V | |

Product Marking

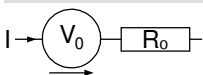


| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSS2x101-015A | DSS2x101-015A | Tube | 10 | 478474 |

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 150^{\circ}C$



Schottky

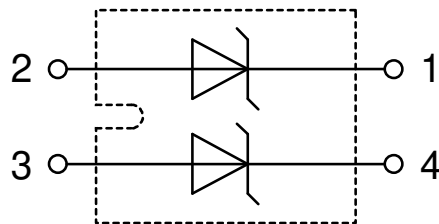
| | | | |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage | 0.53 | V |
| $R_{0\ max}$ | slope resistance * | 0.2 | mΩ |



Outlines SOT-227B (minibloc)



| Dim. | Millimeter | | Inches | |
|------|------------|-------|--------|-------|
| | min | max | min | max |
| A | 31.50 | 31.88 | 1.240 | 1.255 |
| B | 7.80 | 8.20 | 0.307 | 0.323 |
| C | 4.09 | 4.29 | 0.161 | 0.169 |
| D | 4.09 | 4.29 | 0.161 | 0.169 |
| E | 4.09 | 4.29 | 0.161 | 0.169 |
| F | 14.91 | 15.11 | 0.587 | 0.595 |
| G | 30.12 | 30.30 | 1.186 | 1.193 |
| H | 37.80 | 38.23 | 1.488 | 1.505 |
| J | 11.68 | 12.22 | 0.460 | 0.481 |
| K | 8.92 | 9.60 | 0.351 | 0.378 |
| L | 0.74 | 0.84 | 0.029 | 0.033 |
| M | 12.50 | 13.10 | 0.492 | 0.516 |
| N | 25.15 | 25.42 | 0.990 | 1.001 |
| O | 1.95 | 2.13 | 0.077 | 0.084 |
| P | 4.95 | 6.20 | 0.195 | 0.244 |
| Q | 26.54 | 26.90 | 1.045 | 1.059 |
| R | 3.94 | 4.42 | 0.155 | 0.167 |
| S | 4.55 | 4.85 | 0.179 | 0.191 |
| T | 24.59 | 25.25 | 0.968 | 0.994 |
| U | -0.05 | 0.10 | -0.002 | 0.004 |
| V | 3.20 | 5.50 | 0.126 | 0.217 |
| W | 19.81 | 21.08 | 0.780 | 0.830 |
| Z | 2.50 | 2.70 | 0.098 | 0.106 |





Schottky

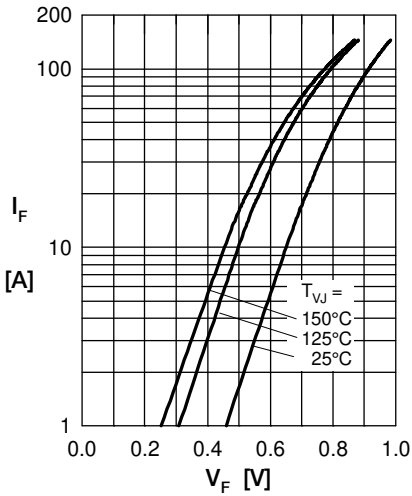


Fig. 1 Max. forward voltage drop characteristics

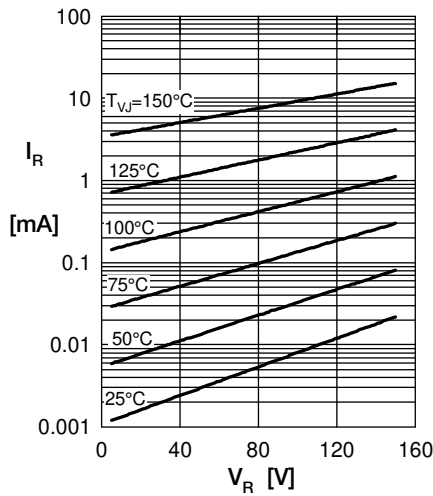


Fig. 2 Typ. reverse current I_R vs. reverse voltage V_R

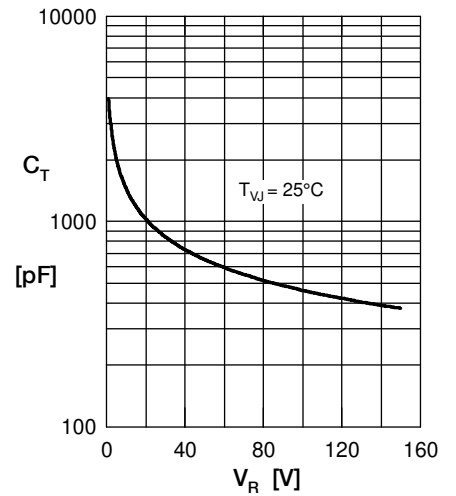


Fig. 3 Typ. junction capacitance C_T vs. reverse voltage V_R

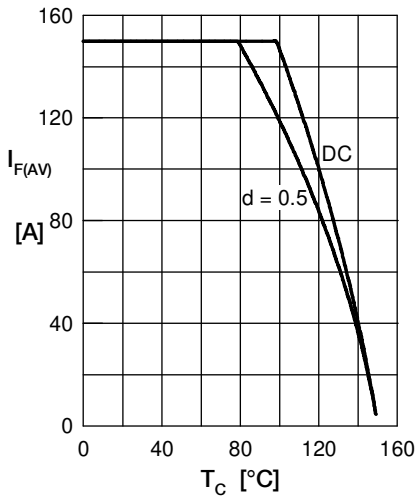


Fig. 4 Average forward current $I_{F(AV)}$ vs. case temp. T_C

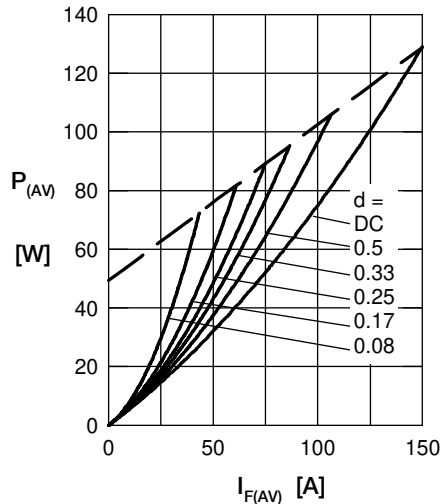


Fig. 5 Forward power loss characteristics

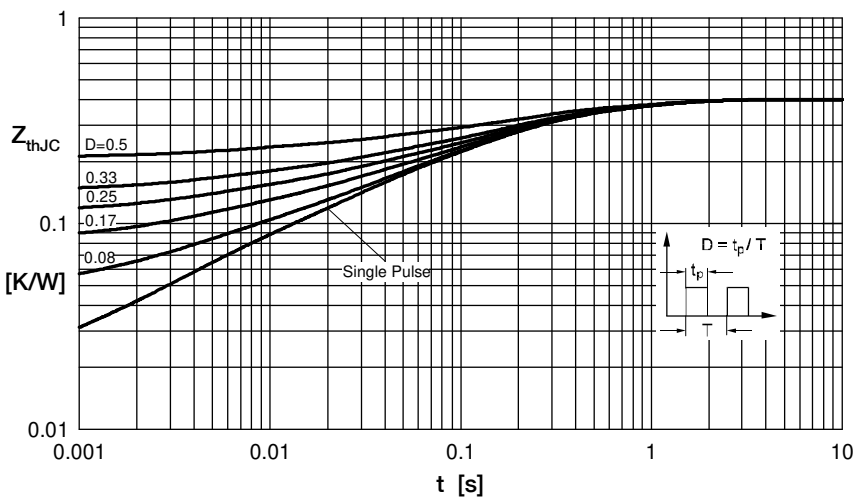


Fig. 6 Transient thermal impedance junction to case at various duty cycles

Note: All curves are per diode